

## Supplementary Information

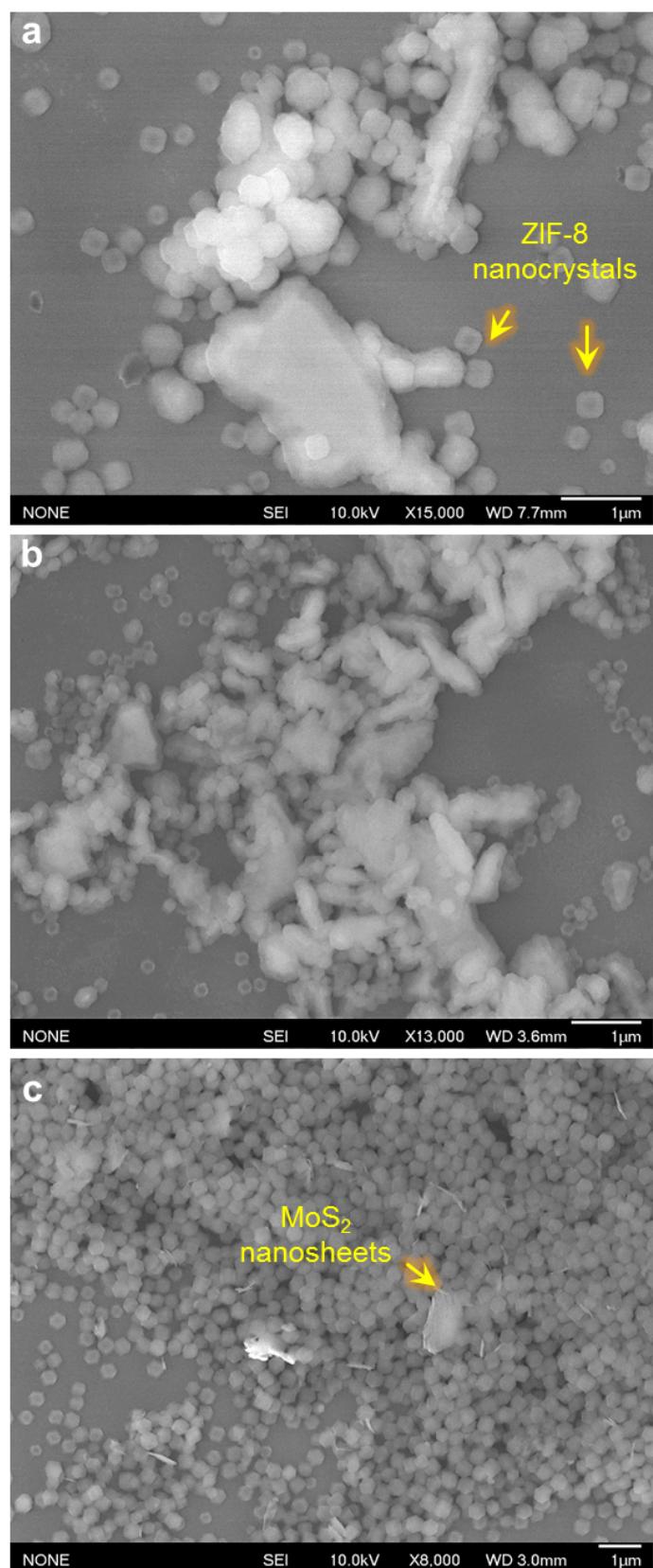
### Supercapacitive Energy Storage Performance of Molybdenum Disulfide Nanosheets Wrapped with Microporous Carbons

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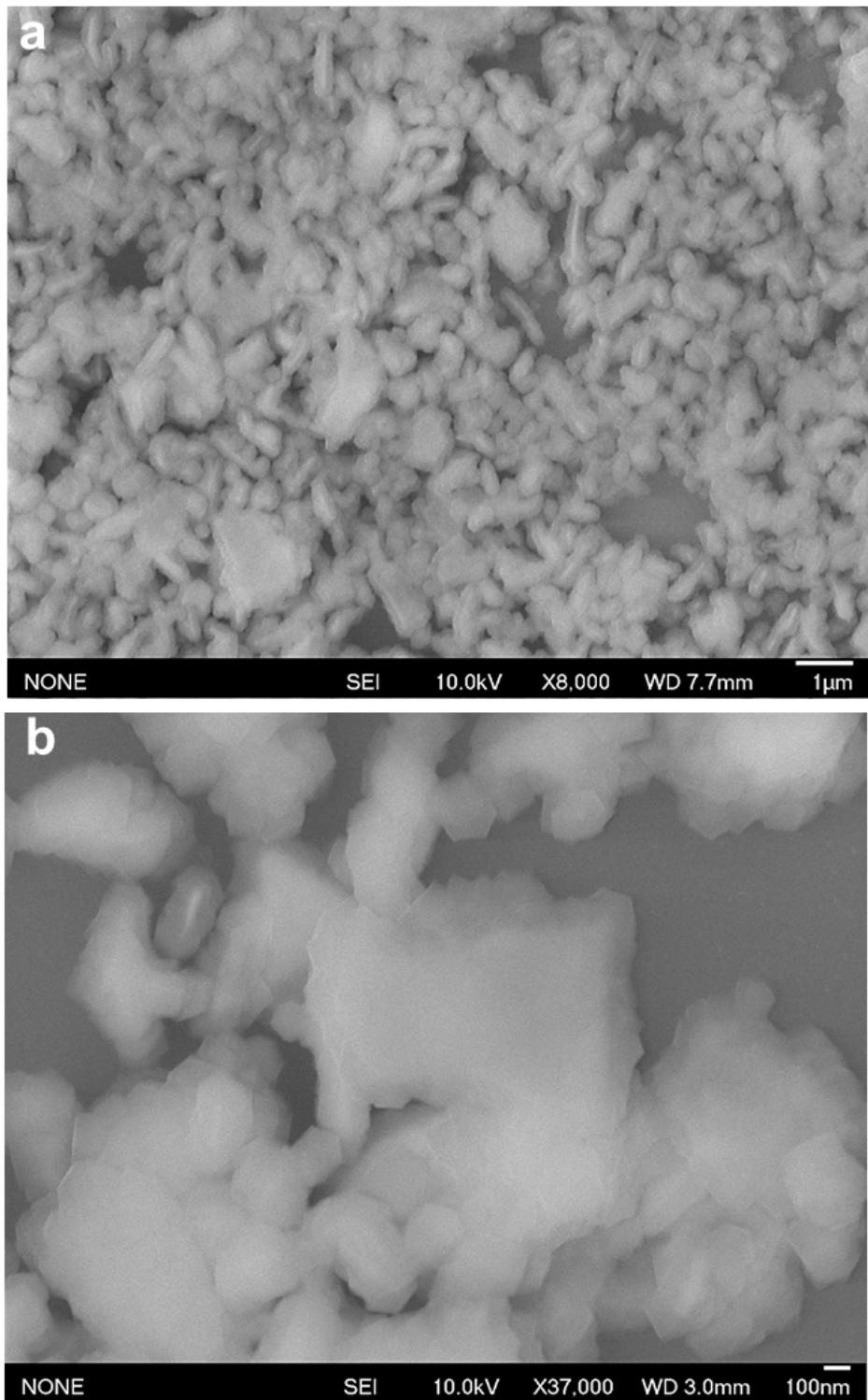
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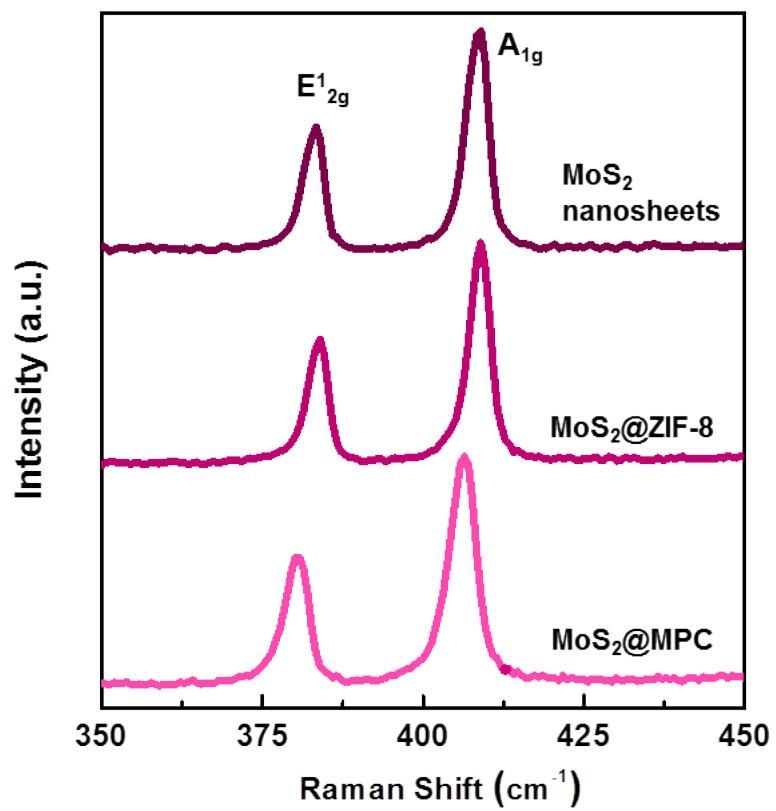
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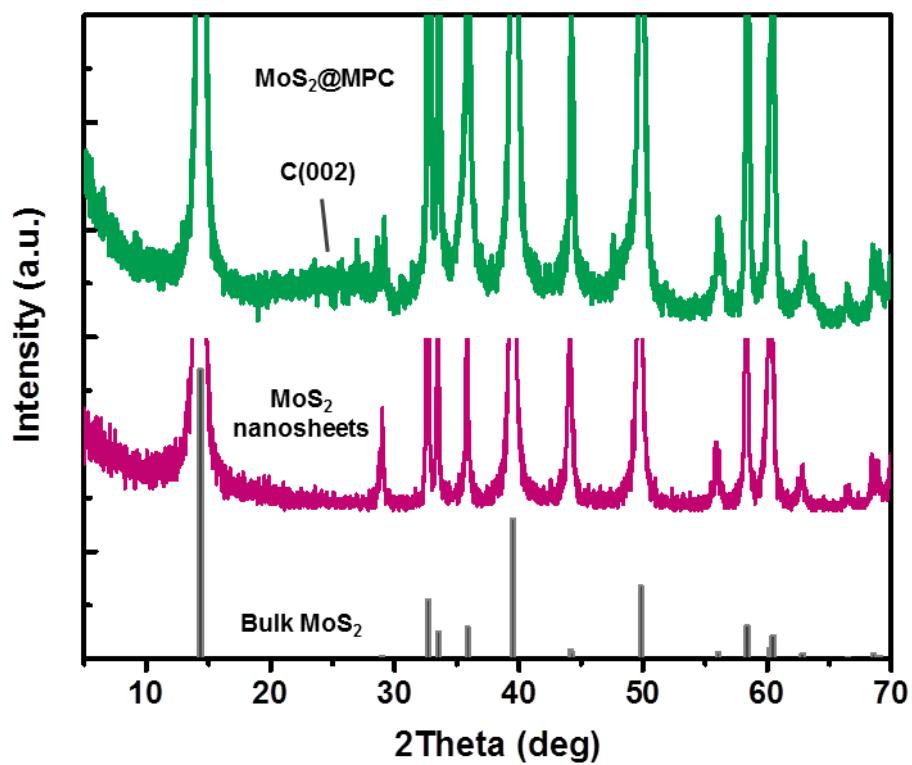
**Fig. S1** SEM images of the products prepared at the mass ratios of  $\text{MoS}_2:\text{Zn}(\text{Ac})_2\cdot 2\text{H}_2\text{O}:\text{MeIM} = 0.18:10:30$  (a) and  $0.36:10:30$  (b) in a 1:4 (v/v)  $\text{H}_2\text{O}/\text{ethanol}$  solution, and  $0.9:10:30$  in a  $\text{H}_2\text{O}$  solution (c).



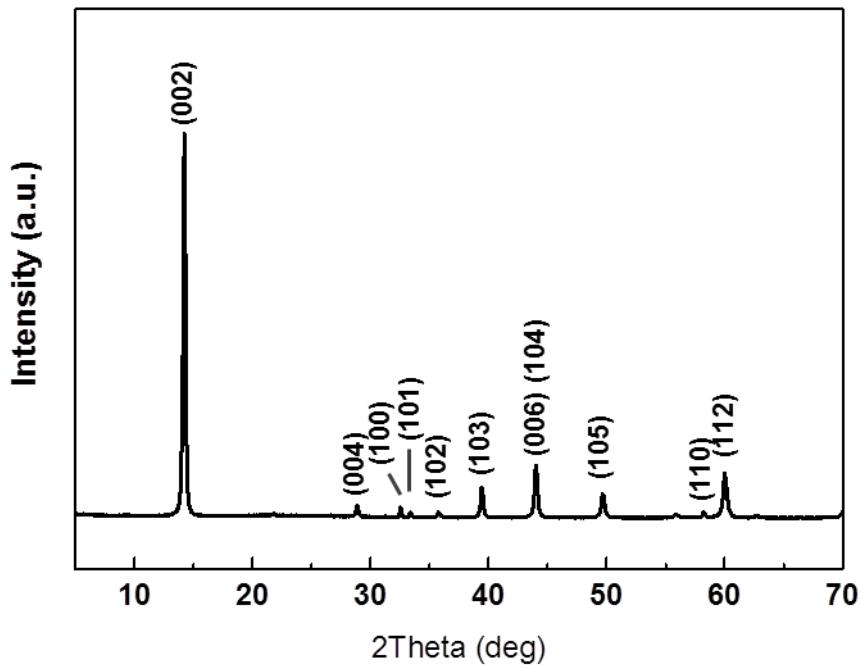
**Fig. S2** Low- (a) and high-magnification (b) SEM images of the  $\text{MoS}_2@\text{ZIF-8}$  sample prepared at the optimized condition (mass ratio for  $\text{MoS}_2$ ,  $\text{Zn}(\text{Ac})_2 \cdot 2\text{H}_2\text{O}$  is 0.9:10:30 in a 1:4 (v/v)  $\text{H}_2\text{O}/\text{ethanol}$  solution).



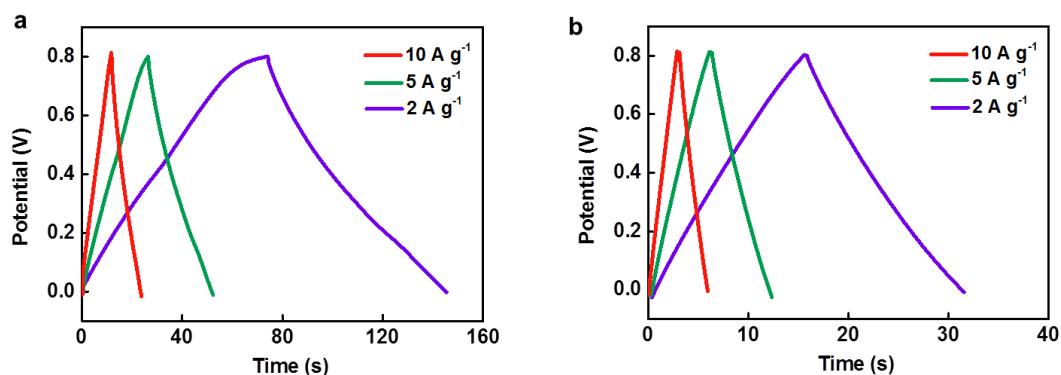
**Fig. S3** Raman spectra of MoS<sub>2</sub> nanosheets, MoS<sub>2</sub>@ZIF-8 and MoS<sub>2</sub>@MPC.



**Fig. S4** Enlarged XRD patterns of MoS<sub>2</sub>@MPC and MoS<sub>2</sub> nanosheets. Standard bulk MoS<sub>2</sub> (JCPDS 651951) diffraction pattern is also added. The C(002) diffraction pattern arisen from MPC shells is also revealed.



**Fig. S4** XRD pattern of MoS<sub>2</sub> nanosheet sample after treatment at 900 °C in Ar for 2 h. The change of the relative intensity of diffraction patterns may be caused by the different XRD experimental conditions. The sample was dispersed in ethanol firstly and then dropped on XRD glass substrate. After vacuum drying, the sample was used for XRD data collection. In this process, a self-assembly-caused preferred orientation of MoS<sub>2</sub> facets may take place. This leads to a different relative diffraction intensity compared with the standard powder method.



**Fig. S5** Charge–discharge curves of MOS<sub>2</sub>@MPC (a) and a mixture of MoS<sub>2</sub> and MPC (m:m = 3:2) (b) at different current densities.

**Table S1** Comparison of the properties of different MoS<sub>2</sub> and MoS<sub>2</sub>-C materials for supercapacitor.

Electrode material	Electrolyte	Maximum specific capacitance	Rate performance	Final capacitance compared to the initial capacitance	Ref.
MoS <sub>2</sub> nanowall films	0.5 M H <sub>2</sub> SO <sub>4</sub>	100 F g <sup>-1</sup> at 1 mV s <sup>-1</sup>	--	--	9
MoS <sub>2</sub> nanosheets	1.0 M Na <sub>2</sub> SO <sub>4</sub>	129.2 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	57.1 %, 10 A g <sup>-1</sup>	85.1 % (after 500 cycles at 1 A g <sup>-1</sup> )	S1
Sphere-like MoS <sub>2</sub> nanostructrues	1.0 M Na <sub>2</sub> SO <sub>4</sub>	92.85 F g <sup>-1</sup> at 0.5 mA cm <sup>-2</sup>	--	93.8 % (after 1000 cycles at 0.5 mA cm <sup>-2</sup> )	11
Porous tubular C/MoS <sub>2</sub> nanocomposite s	3.0 M KOH	210 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	~36 %, 4 A g <sup>-1</sup>	105 % (after 1000 cycles at 4 A g <sup>-1</sup> )	S2
MoS <sub>2</sub> /CNTs composites	1.0 M Na <sub>2</sub> SO <sub>4</sub>	452.7 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	73.7%, 10 A g <sup>-1</sup>	95.8 % (after 1000 cycles at 1 A g <sup>-1</sup> )	12
Low Concentration MoS <sub>2</sub> /RGO	1.0 M HClO <sub>4</sub>	128 F g <sup>-1</sup> at 10 mV s <sup>-1</sup>	~72 %, 80 mV s <sup>-1</sup>	92 % (after 1000 cycles at 20 mV s <sup>-1</sup> )	10
Medium Concentration MoS <sub>2</sub> /RGO		265 F g <sup>-1</sup> at 10 mV s <sup>-1</sup>	~96 %, 80 mV s <sup>-1</sup>	70 % (after 1000 cycles at 20 mV s <sup>-1</sup> )	
High Concentration MoS <sub>2</sub> /RGO		148 F g <sup>-1</sup> at 10 mV s <sup>-1</sup>	~71 %, 80 mV s <sup>-1</sup>	--	
MoS <sub>2</sub> @MPC	1.0 M H <sub>2</sub> SO <sub>4</sub>	189 F g <sup>-1</sup> at 1 A g <sup>-1</sup>	70.5 %, 20 A g <sup>-1</sup>	98 % (after 3000 cycles at 10 A g <sup>-1</sup> )	This work

## References

- S1. K. J. Huang, J. Z. Zhang, G. W. Shi, Y. M. Liu, *Electrochim. Acta*, 2014, **132**, 397.  
 S2. B. L. Hu, X. Y. Qin, A. M. Asiri, K. A. Alamry, A. O. Al-Youbi, X. P. Sun, *Electrochim. Acta*, 2013, **100**, 24.